1. General description

PNP medium power transistors in an ultra thin DFN2020D-3 (SOT1061D) leadless small Surface-Mounted Device (SMD) plastic package with medium power capability and Side-Wettable Flanks (SWF).

2. Features and benefits

- High collector current capability I_C and I_{CM}
- Reduced Printed-Circuit Board (PCB) area requirements
- Leadless small SMD plastic package with solderable side pads
- Exposed heatsink for excellent thermal and electrical conductivity
- · Suitable for Automatic Optical Inspection (AOI) of solder point
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Linear voltage regulators
- · High-side switches
- · Battery-driven devices
- MOSFET drivers
- Amplifiers

4. Quick reference data

Table 1. Quick reference data

Table 1. Quick reference data							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	-80	V
I _C	collector current			-	-	-1	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	-2	Α
h _{FE}	DC current gain	V_{CE} = -5 V; I_{C} = -100 mA; pulsed; $t_{p} \le$ 300 μs; $\delta \le$ 0.01; T_{amb} = 25 °C		100	-	300	



80 V, 1 A PNP medium power transistor

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	
2	Е	emitter		С
3	С	collector	Transparent top view DFN2020D-3 (SOT1061D)	B — E 006aaa231

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BSR33PAS-Q	DFN2020D-3	plastic, leadless thermal enhanced ultra thin small outline package with side-wettable flanks (SWF); no leads; 3 terminals; 1.3 mm pitch; 2 mm x 2 mm x 0.65 mm body	SOT1061D		

7. Marking

Table 4. Marking codes

Type number	Marking code
BSR33PAS-Q	G3

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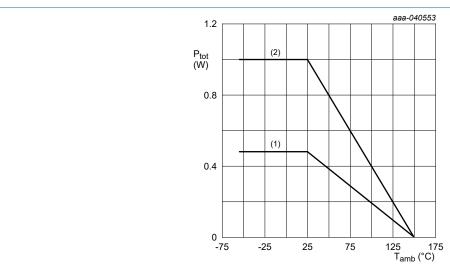
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	-90	V
V _{CEO}	collector-emitter voltage	open base		-	-80	V
V _{EBO}	emitter-base voltage	open collector		-	-5	V
I _C	collector current			-	-1	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-2	Α
I _{BM}	peak base current			-	-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	0.48	W
			[2]	-	1	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

- Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, and standard footprint. Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².



- (1) FR4 PCB, single-sided copper, standard footprint
- (2) FR4 PCB, single-sided copper, 1 cm²

Power derating curves Fig. 1.

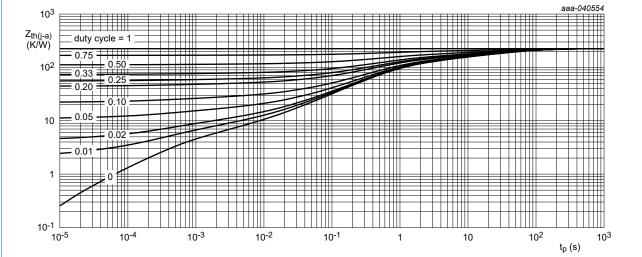
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9. Thermal characteristics

Table 6. Thermal characteristics

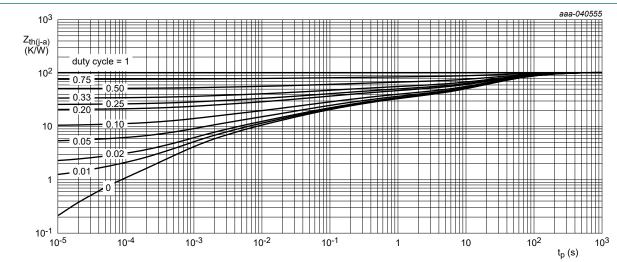
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from	in free air	[1]	-	-	260	K/W
junction to ambient		[2]	-	-	125	K/W	
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	-	12	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².



FR4 PCB,single-sided, 70 µm copper, standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided, 70 µm copper, mounting pad for collector 1 cm²

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

80 V, 1 A PNP medium power transistor

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V _{CB} = -60 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-100	nA
	current (emitter open)	V _{CB} = -60 V; I _E = 0 A; T _j = 150 °C	-	-	-50	μA
I _{EBO}	emitter-base cut-off current (collector open)	$V_{EB} = -5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	-	-	-100	nA
h _{FE}	DC current gain	V_{CE} = -5 V; I_{C} = -100 μA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.01; T_{amb} = 25 °C	30	-	-	
		V_{CE} = -5 V; I_{C} = -100 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.01; T_{amb} = 25 °C	100	-	300	
		V_{CE} = -5 V; I_{C} = -500 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.01; T_{amb} = 25 °C	50	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = -150 mA; I_B = -15 mA; pulsed; $t_p \le$ 300 μs; $\delta \le$ 0.01; T_{amb} = 25 °C	-	-	-0.25	V
		I_C = -500 mA; I_B = -50 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.01; T_{amb} = 25 °C	-	-	-0.5	V
V _{BEsat}	base-emitter saturation voltage	I_C = -150 mA; I_B = -15 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.01; T_{amb} = 25 °C	-	-	-1	V
		I_C = -500 mA; I_B = -50 mA; pulsed; $t_p \le$ 300 μs; $\delta \le$ 0.01; T_{amb} = 25 °C	-	-	-1.2	V
f _T	transition frequency	V_{CE} = -10 V; I_{C} = -50 mA; f = 100 MHz; T_{amb} = 25 °C	100	-	-	MHz

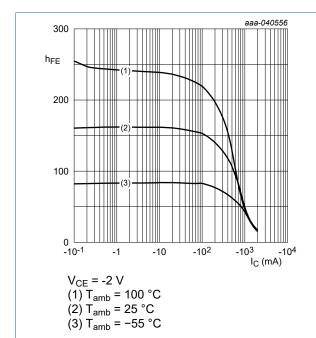


Fig. 4. DC current gain as a function of collector current; typical values

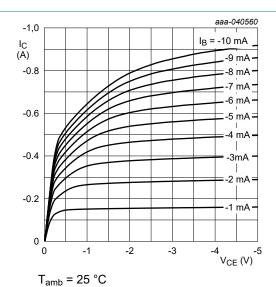


Fig. 5. Collector current as a function of collectoremitter voltage; typical values

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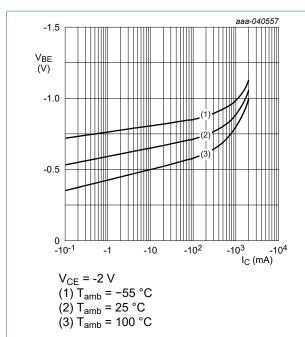


Fig. 6. Base-emitter voltage as a function of collector current; typical values

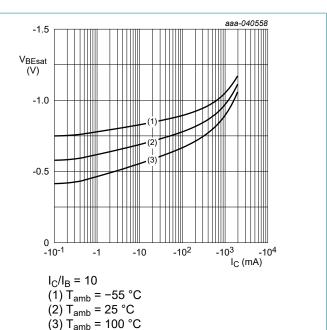
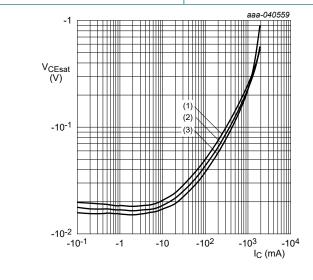


Fig. 7. Base-emitter saturation voltage as a function of collector current; typical values



 $I_{C}/I_{B} = 10$ (1) $T_{amb} = 100 \,^{\circ}C$

(2) $T_{amb} = 25 \, ^{\circ}C$

(3) $T_{amb} = -55 \, ^{\circ}C$

Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values

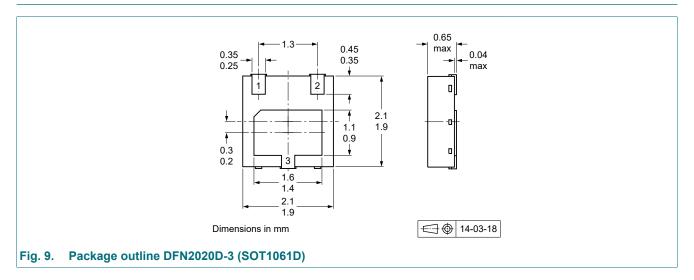
11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

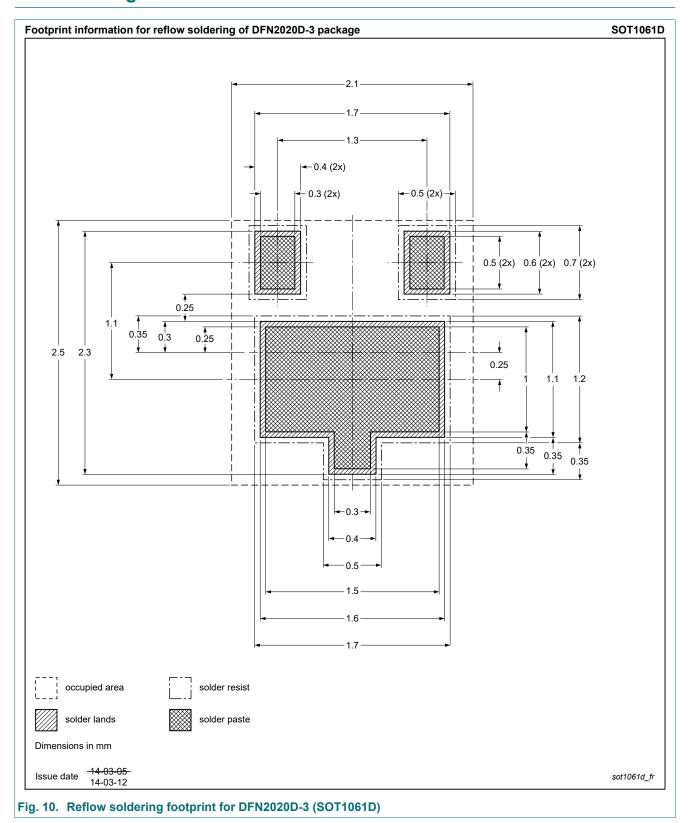
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12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BSR33PAS-Q v.1	20240909	Product data sheet	-	-

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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